



1.5V, 3V Strobe Applications

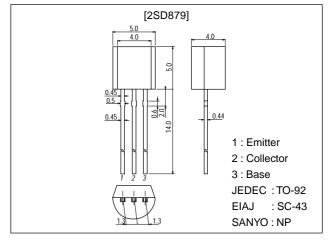
Features

- · In applications where two NiCd batteries are used to provide 2.4V, two 2SD879s are used.
- The charge time is approximately 1 second faster than that of germanium transistors.
- \cdot Less power dissipation because of low Collector-to-Emitter Voltage $V_{CE(sat)},$ permitting more flashes of light to be emitted.
- · Small package and large allowable collector dissipation (TO-92, PC=750mW).
- Large current capacity and highly resistant to breakdown.
- \cdot Excellent linearity of $h_{\mbox{\scriptsize FE}}$ in the region from low current to high current.

Package Dimensions

unit:mm

2003B



Specifications

Absolute Maximum Ratings at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|------------------------------|------------------|--------------------|-------------|------|
| Collector-to-Base Voltage | V _{CBO} | | 30 | V |
| Collector-to-Emitter Voltage | VCEX | | 20 | V |
| | VCEO | | 10 | V |
| Emitter-to-Base Voltage | V _{EBO} | | 6 | V |
| Collector Current | IС | | 3 | Α |
| Collector Current (Pulse) | I _{CP} | 100ms single pulse | 5 | Α |
| Collector Dissipation | PC | | 750 | mW |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta = 25°C

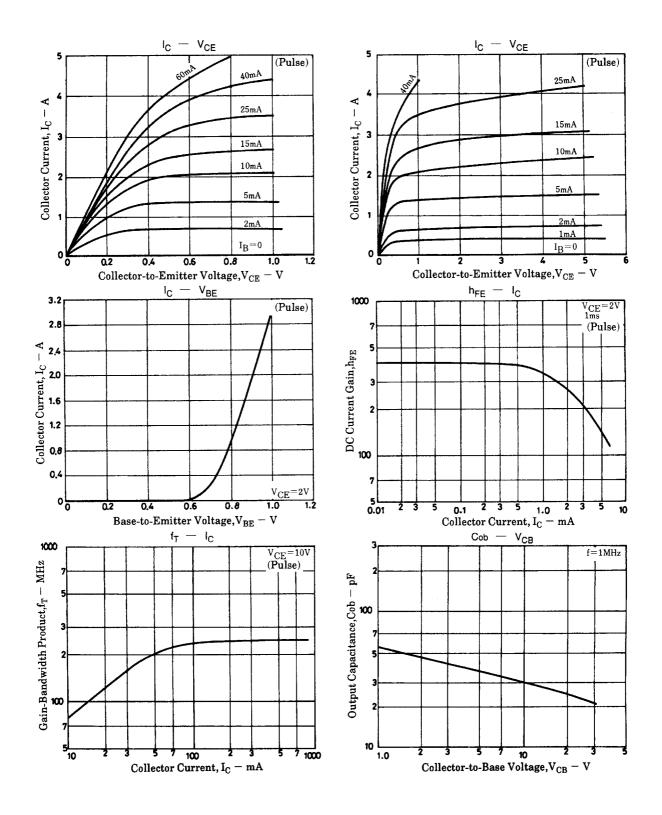
| Parameter | Symbol | Conditions | Ratings | | | Unit |
|---|------------------|--|---------|-----|-----|---------|
| | Symbol | | min | typ | max | l Ollit |
| Collector Cutoff Current | ICBO | V _{CB} =20V, I _E =0 | | | 1.0 | μΑ |
| Emitter Cutoff Current | I _{EBO} | V _{EB} =4V, I _C =0 | | | 1.0 | μΑ |
| DC Current Gain | hFE | V _{CE} =2V, I _C =3A (pulse) | 140 | 210 | | |
| Gain-Bandwidth Product | fT | V _{CE} =10V, I _C =50mA | | 200 | | MHz |
| Output Capacitance | C _{ob} | V _{CB} =10V, f=1MHz | | 30 | | pF |
| Collector-to-Emitter Saturation Voltage | VCE(sat) | I _C =3A, I _B =60mA (pulse) | | 0.3 | 0.4 | V |

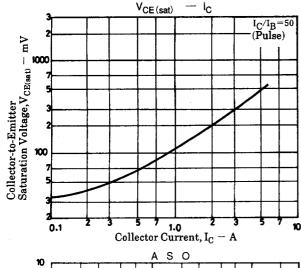
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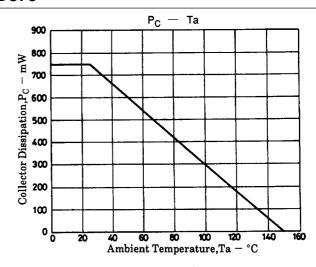
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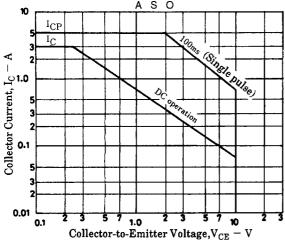
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| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|----------------------|--|---------|-----|-----|-------|
| | | | min | typ | max | Oilit |
| Collector-to-Base Breakdown Voltage | V(BR)CBO | I _C =10μA, I _E =0 | 30 | | | V |
| Collector-to-Emitter Breakdown Voltage | V _{(BR)CEX} | I _C =1mA, V _{BE} =3V | 20 | | | V |
| | V(BR)CEO | I _C =1mA, R _{BE} =∞ | 10 | | | V |
| Emitter-to-Base Breakdown Voltage | V(BR)EBO | I _E =10μA, I _C =0 | 6 | | | V |

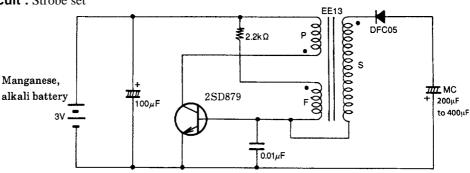




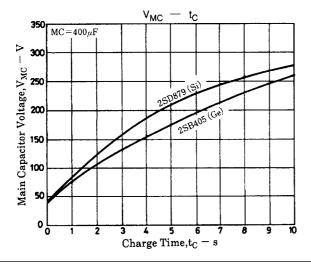


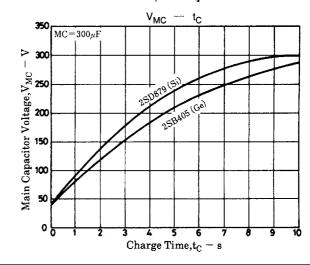


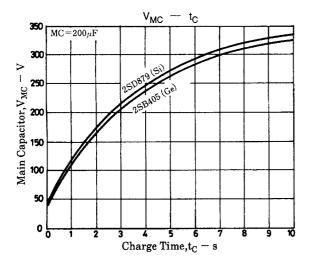
Sample Application Circuit: Strobe set



Core : EE13 (Kijima Wireless) Number of turns specified for transformer $~P:0.55~\phi\times10~3/_{4}T,~S:0.07~\phi\times1350T$ $~F:0.23~\phi\times12~3/_{4}T$







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